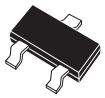
查询CMPTA96供应商

CMPTA96

SURFACE MOUNT
PNP SILICON
EXTREMELY HIGH VOLTAGE
TRANSISTOR



SOT-23 CASE

Central™
Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMPTA96 type is a surface mount epoxy molded PNP silicon planar epitaxial transistors designed for extremely high voltage applications. **Marking Code is C96.**

MAXIMUM RATINGS: (T_A=25°C)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	450	V
Collector-Emitter Voltage	V_{CEO}	450	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current	I_C	500	mA
Power Dissipation	P_D	350	mW
Operating and Storage Junction Temperature	T_J,T_{stg}	-65 to +150	°C
Thermal Resistance	Θ_{JA}	357	°C/W

ELECTRICAL CHARACTERISTICS:

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CBO}	V_{CB}=400V			100	nA
I_{EBO}	V_{BE}=4.0V			100	nA
BV_{CBO}	I_C=100μA	450	500		V
BV_{CEO}	I_C=1.0mA	450	490		V
BV_{EBO}	I_E=10μA	6.0	9.7		V
$V_{CE(SAT)}$	I_C=1.0mA, I_B=0.1mA			0.20	V
$V_{CE(SAT)}$	I_C=10mA, I_B=1.0mA			0.30	V
$V_{CE(SAT)}$	I_C=50mA, I_B=5.0mA		0.15	0.50	V
$V_{BE(SAT)}$	I_C=10mA, I_B=1.0mA			1.0	V
h_{FE}	V_{CE}=10V, I_C=1.0mA	40			
h_{FE}	V_{CE}=10V, I_C=10mA	50	120	200	
h_{FE}	V_{CE}=10V, I_C=50mA	45			
h_{FE}	V_{CE}=10V, I_C=100mA	25	35		
f_T	V_{CE}=10V, I_C=10mA, f=10MHz	20			MHz
C_{ob}	V_{CB}=20V, I_E=0, f=1.0MHz			7.0	pF
C_{ib}	V_{EB}=0.5V, I_C=0, f=1.0MHz			130	

R1 (14-June2001)

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CMPTA96

SURFACE MOUNT
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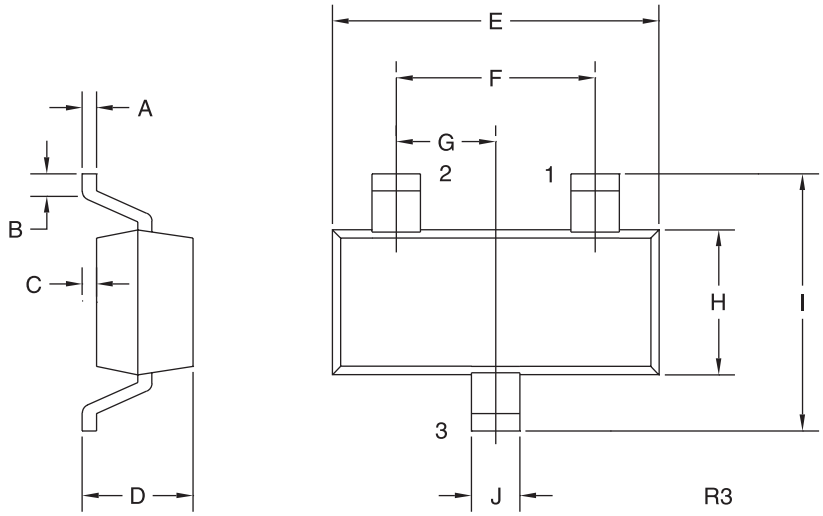
SOT-23 CASE - MECHANICAL OUTLINE



LEAD CODE:

1) BASE
2) EMITTER
3) COLLECTOR

MARKING CODE: C96

DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
A	0.003	0.007	0.08	0.18
B	0.006	-	0.15	-
C	-	0.005	-	0.13
D	0.035	0.043	0.89	1.09
E	0.110	0.120	2.80	3.05
F	0.075		1.90	
G	0.037		0.95	
H	0.047	0.055	1.19	1.40
I	0.083	0.098	2.10	2.49
J	0.014	0.020	0.35	0.50

SOT-23 (REV: R3)

R1 (14-June2001)